2SC1847

Silicon NPN epitaxial planar type

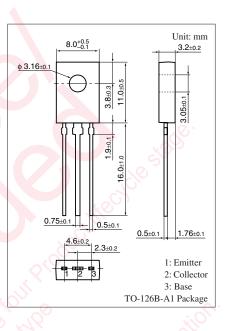
For medium output power amplification Complementary to 2SA0886

Features

- Output of 4 W can be obtained by a complementary pair with 2SA0886
- TO-126B package which requires no insulation plate for installation to the heat sink

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	50	V	
Collector-emitter voltage (Base open)	V _{CEO}	40	v	
Emitter-base voltage (Collector open)	V _{EBO}	5	V	
Collector current	I _C	1.5	А	
Peak collector current	I _{CP}	3	A	
Collector power dissipation	P _C	1.2	W	
Junction temperature	Tj	150	°CO	
Storage temperature	T _{stg}	-55 to +150	°C	



Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

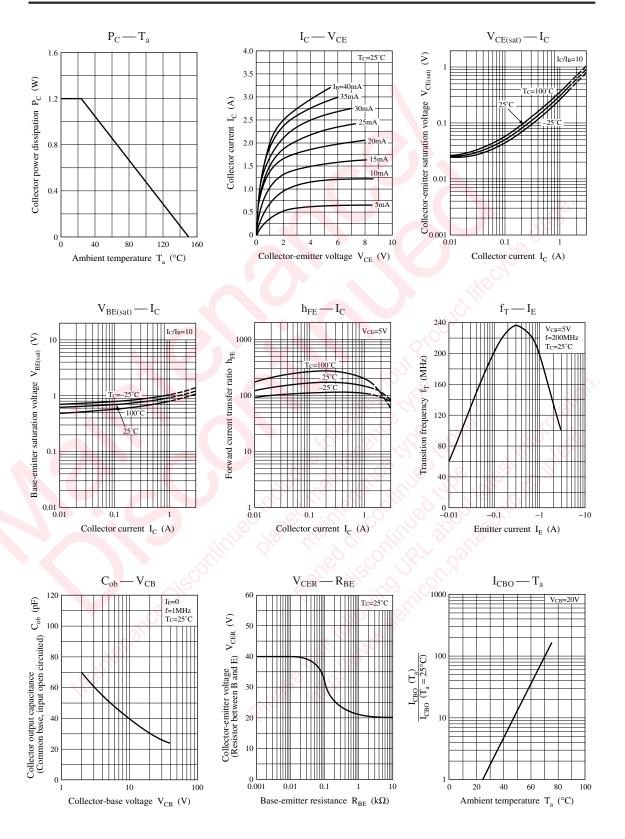
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 1 \text{ mA}, I_{\rm E} = 0$	50	S		V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	40	^o		V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 20 V, I_E = 0$	2		1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 10 V, I_B = 0$			100	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 5 V, I_C = 0$			10	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CE} = 5 V, I_C = 1 A$	80		220	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 2 {\rm A}, I_{\rm B} = 0.2 {\rm A}$			1	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_{\rm C} = 2 {\rm A}, I_{\rm B} = 0.2 {\rm A}$			1.5	V
Transition frequency	f _T	$V_{CB} = 5 V, I_E = -0.5 A, f = 200 MHz$		150		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 20 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		35		pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

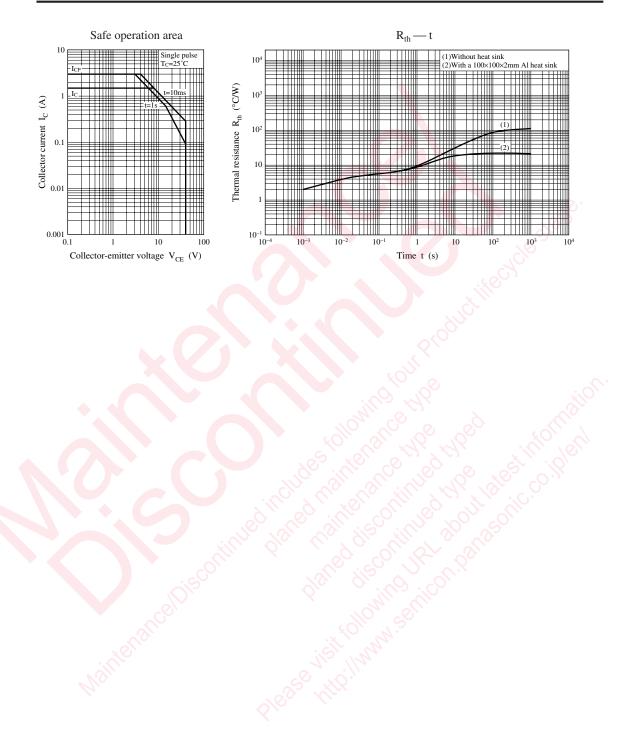
2. *: Rank classification

Rank	Q	R
$h_{\rm FE}$	80 to 160	120 to 220

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